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Kind regards,

Team Nexperia

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

Rev. 6 — 4 January 2012

Product data sheet

1. Product profile

1.1 General description

NPN/PNP Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	number Package		PNP/PNP		Package
	NXP	JEITA	complement	complement	configuration
PEMD10	SOT666	-	PEMB10	PEMH10	ultra small and flat lead
PUMD10	SOT363	SC-88	PUMB10	PUMH10	very small

Reduces component countReduces pick and place costs

AEC-Q101 qualified

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

1.4 Quick reference data

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transi	istor; for the PNP transistor	(TR2) with negati	ve polarity			
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
lo	output current		-	-	100	mA
R1	bias resistor 1 (input)		1.54	2.20	2.86	kΩ
R2/R1	bias resistor ratio		17	21	26	



| | 2 3 006aaa143

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	GND (emitter) TR1		
2	input (base) TR1	6 5 4	
3	output (collector) TR2		
4	GND (emitter) TR2		
5	input (base) TR2		
6	output (collector) TR1	001aab555	

3. Ordering information

Table 4.Ordering information

Type number	Package	Package		
	Name	Description	Version	
PEMD10	-	plastic surface-mounted package; 6 leads	SOT666	
PUMD10	SC-88	plastic surface-mounted package; 6 leads	SOT363	

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
PEMD10	D1
PUMD10	D*0

[1] * = placeholder for manufacturing site code.

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

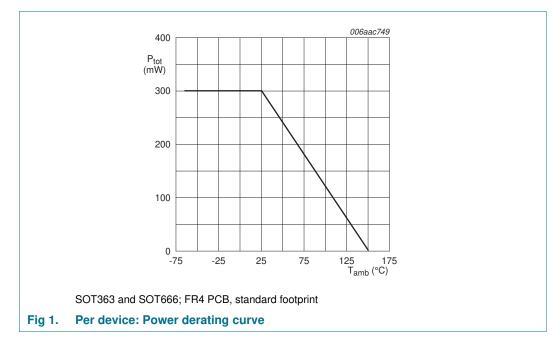
5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor; for the PNP transistor	(TR2) with negative	polarity		
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
VI	input voltage TR1				
	positive		-	+12	V
	negative		-	-5	V
	input voltage TR2				
	positive		-	+5	V
	negative		-	-12	V
lo	output current		-	100	mA
I _{CM}	peak collector current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1]		
	PEMD10 (SOT666)		[2] _	200	mW
	PUMD10 (SOT363)		-	200	mW
Per device)				
P _{tot}	total power dissipation	$T_{amb} \leq 25 \ ^{\circ}C$	[1]		
	PEMD10 (SOT666)		[2] _	300	mW
	PUMD10 (SOT363)		-	300	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω



6. Thermal characteristics

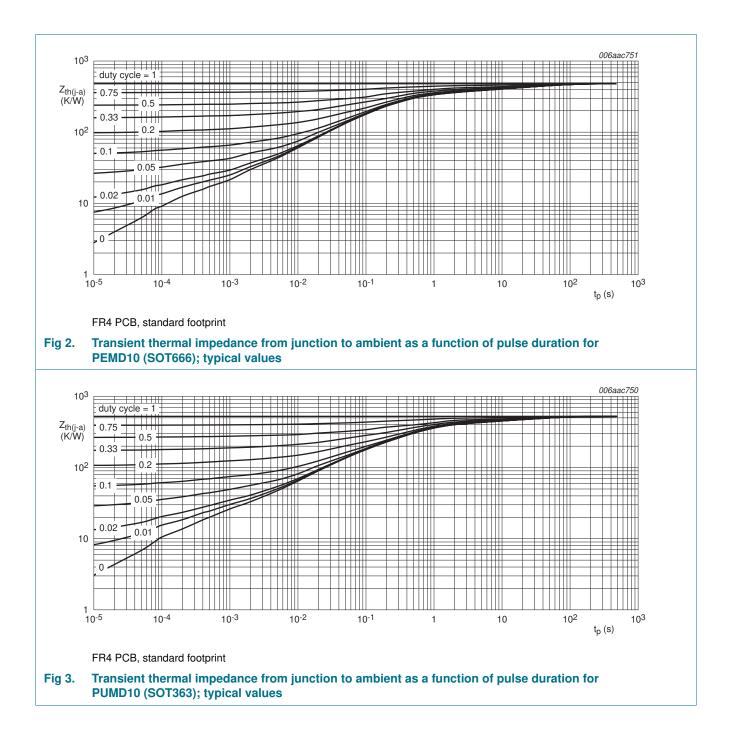
Table 7.	Thermal characteristic	S				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	sistor					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]			
	PEMD10 (SOT666)		[2] _	-	625	K/W
	PUMD10 (SOT363)		-	-	625	K/W
Per devi	се					
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	PEMD10 (SOT666)		[2] _	-	417	K/W
	PUMD10 (SOT363)		-	-	417	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

PEMD10_PUMD10
Product data sheet

PEMD10; PUMD10



NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

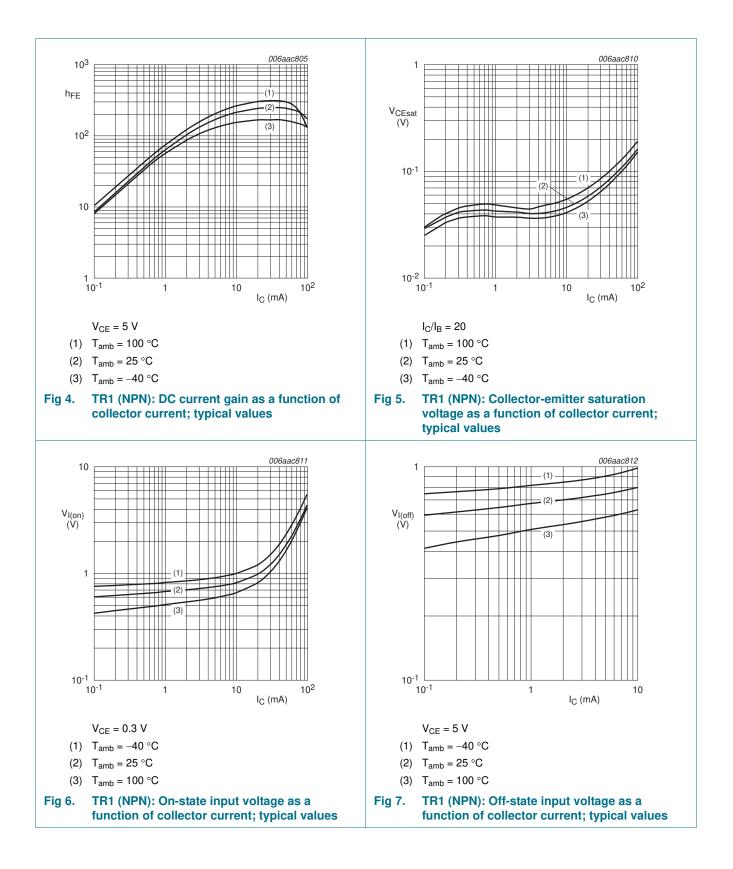
7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per trans	istor; for the PNP tran	sistor (TR2) with negative p	olarity			
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_B = 0 \text{ A}$	-	-	100	nA
		$\label{eq:VCE} \begin{array}{l} V_{CE} = 30 \; V; \; I_{B} = 0 \; A; \\ T_{j} = 150 \; ^{\circ}C \end{array}$	-	-	5	μ A
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	180	μ A
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = 5 \text{ mA}; I_{B} = 0.25 \text{ mA}$	-	-	100	mV
V _{I(off)}	off-state input voltage	$V_{CE} = 5 \text{ V}; \text{ I}_{C} = 100 \mu\text{A}$	-	0.6	0.5	V
V _{I(on)}	on-state input voltage	$V_{CE}=0.3 \text{ V; } I_C=5 \text{ mA}$	1.1	0.75	-	V
R1	bias resistor 1 (input)		1.54	2.20	2.86	kΩ
R2/R1	bias resistor ratio		17	21	26	
C _c	collector capacitance	$\label{eq:VCB} \begin{split} V_{CB} &= 10 \text{ V}; \text{I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} &= 1 \text{ MHz} \end{split}$				
	TR1 (NPN)		-	-	2.5	pF
	TR2 (PNP)		-	-	3	pF
f _T	transition frequency	$\label{eq:VCB} \begin{array}{l} V_{CB} = 5 \text{ V}; \text{ I}_{C} = 10 \text{ mA}; \\ f = 100 \text{ MHz} \end{array}$	[1]			
	TR1 (NPN)		-	230	-	MHz
	TR2 (PNP)		-	180	-	MHz

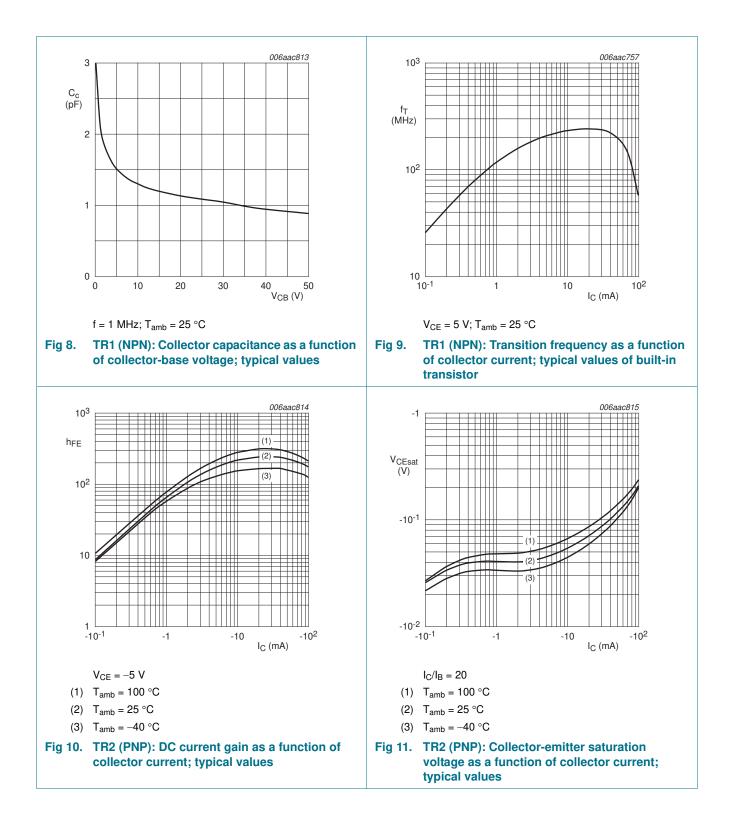
[1] Characteristics of built-in transistor.

PEMD10_PUMD10 Product data sheet

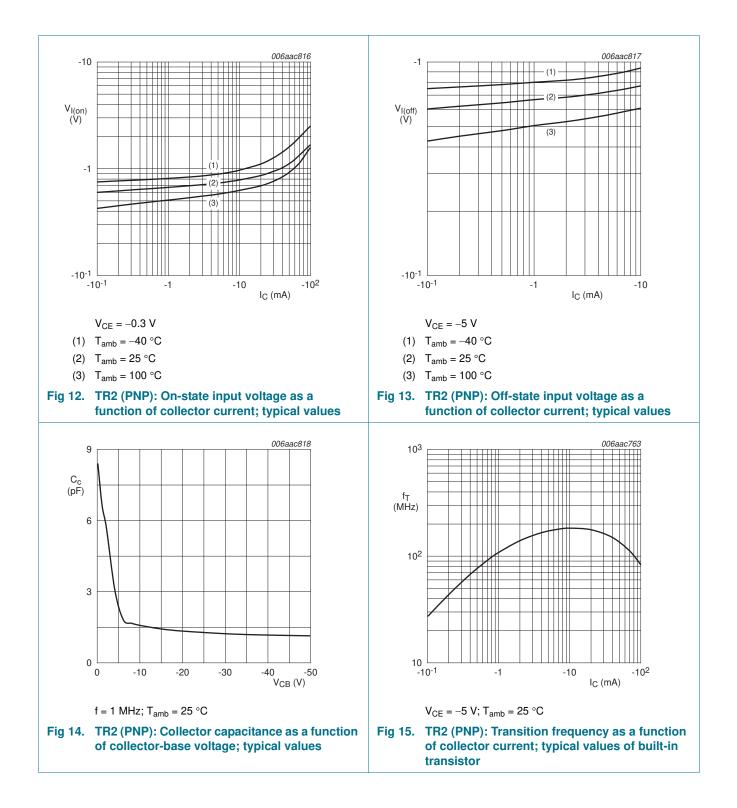
PEMD10; PUMD10



PEMD10; PUMD10



PEMD10; PUMD10



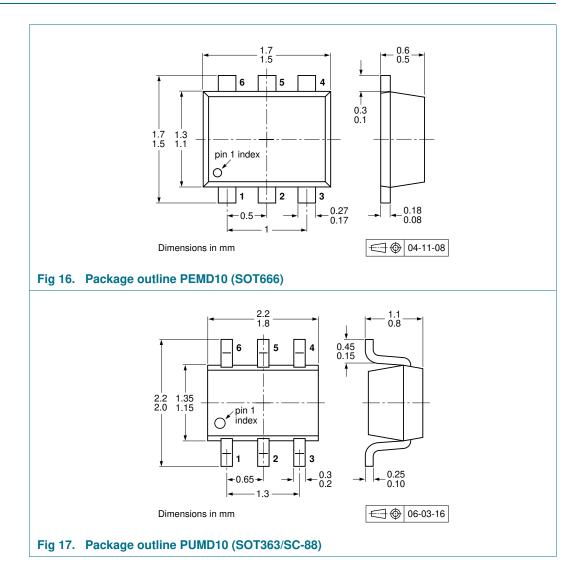
NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

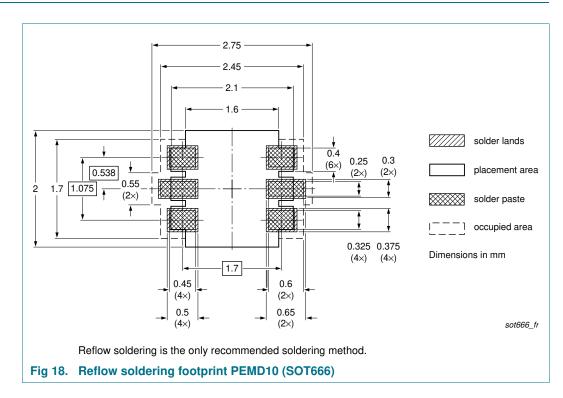
Type number	Package	e Description		Packing quantity			
			3	3000	4000	8000	10000
PEMD10	SOT666	2 mm pitch, 8 mm tape and reel	-		-	-315	-
		4 mm pitch, 8 mm tape and reel	-		-115	-	-
PUMD10	SOT363	4 mm pitch, 8 mm tape and reel; T1	[2] _	115	-	-	-135
		4 mm pitch, 8 mm tape and reel; T2	[3] _	125	-	-	-165

[1] For further information and the availability of packing methods, see Section 14.

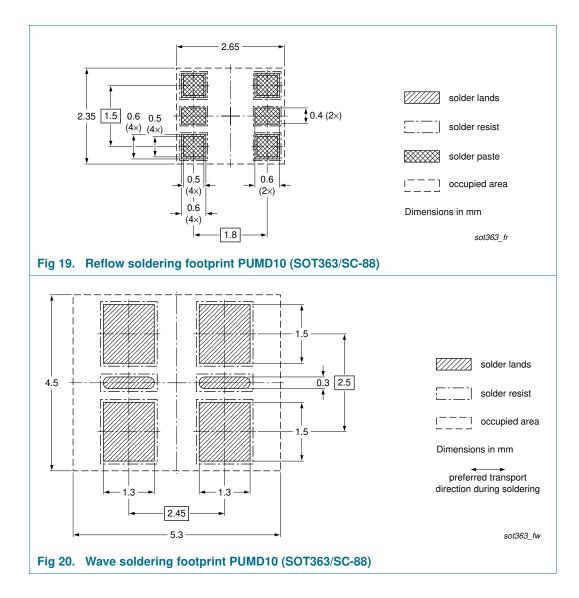
[2] T1: normal taping

[3] T2: reverse taping

11. Soldering



NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω



PEMD10_PUMD10
Product data sheet

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PEMD10_PUMD10 v.6	20120104	Product data sheet	-	PEMD10_PUMD10 v.5			
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 						
	 Legal texts have been adapted to the new company name where appropriate. 						
	<u>Section 1 "Product profile"</u> : updated						
	Section 4 "Marking": updated						
	 <u>Table 6 "Limiting values"</u>: P_{tot} updated according to the latest measurements 						
	Table 7 "Thermal characteristics": updated according to the latest measurements						
	 <u>Table 8 "Characteristics</u>": I_{CEO} updated according to the latest measurements, f_T added 						
	• Figure 1 to 3, 8, 9, 14 and 15: added						
	• Figure 4 to 7 and Figure 10 to 13: updated						
	Section 8 "Test information": added						
	 Section 11 "S 	Soldering": added					
	 Section 13 "I 	<u>_egal information"</u> : updated	b				
PEMD10_PUMD10 v.5	20040415	Product data sheet	-	PEMD10_PUMD10 v.4			
PEMD10_PUMD10 v.4	20031104	Product specification	-	PEMD10 v.2 PUMD10 v.3			

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PEMD10_PUMD10

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

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PEMD10; PUMD10

NPN/PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = 47 k Ω

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